

REMARKS

Claims 1-34 are pending in this broadening reissue application. The Applicant has amended claims 1, 7, and 12 to correct one of the errors described in the reissue declaration and discussed below, and has added new claims 19-34.

The Applicants have amended original independent claims 1, 7, and 12 to remove a limitation that resulted in Applicants claiming less than they had a right to claim. As set forth in the Reissue Declaration, original independent claims 1 and 7 as issued recite "a third patterned thin-film layer comprising substantially undoped polysilicon having a very high resistivity," and original independent claim 12 as issued recites "an additional patterned thin-film layer comprising substantially intrinsic polysilicon." Each of these thin film layers corresponds to layer in which resistors for Static Random Access Memory (SRAM) cells are formed. Regarding these resistors, the specification expressly states in column 4, lines 46-51, that "[a]lthough the resistors are formed from intrinsic polysilicon in the presently preferred embodiment, it will be recognized that a slight amount of doping may be desirable to stabilize the characteristics of this material. For example, this material may be doped with chlorine, or may be SIPOS (containing a large fraction of oxygen)." Thus, the "substantially undoped" language unduly limits the scope of original claims 1 and 7, and the same is true of the "substantially intrinsic" language in original claim 12. Accordingly, the language "substantially undoped" has been deleted in amended claims 1 and 7 and the language "substantially intrinsic" has been deleted in amended claim 12. Newly added dependent claims 19-23 recite further limitations of the layer set forth in the corresponding independent claim that was broadened through the previously discussed amendments.

In view of the foregoing, original independent claims 1, 7, and 12 as amended, original dependent claims 2-6, 8-11, and 13-19, and newly added claims 19-34 are in condition for allowance, and allowance is requested.

If the Examiner believes that a phone interview would be helpful, he is respectfully requested to contact the Applicants' attorney, Paul F. Rusyn, at (425) 455-5575.

Please note that the firm, GRAYBEAL JACKSON HALEY LLP, of Applicants' attorney has recently moved to : 155 – 108th Avenue NE, Suite 350, Bellevue, Washington 98004-5901. The telephone and facsimile numbers remain the same. Please send all future communications to that address.

Respectfully submitted,

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Enclosures